

Revision 0.50

## SINGLE FREQUENCY LASER DIODES Distributed Feedback Laser



### General Product Information

Product	Application
780 nm DFB Laser	Spectroscopy (Rb D2 line)
with hermetic 8-Pin TO Package (RoHS compliant)	Metrology
including Monitor Diode, Thermoelectric Cooler and Thermistor	THz Generation



### Absolute Maximum Ratings

Parameter	Symbol	Unit	min	typ	max
Storage Temperature	T <sub>S</sub>	°C	-40		85
Operational Temperature at Case	$T_{C}$	°C	-20		75
Operational Temperature at Laser Chip	$T_LD$	°C	0		50
Forward Current	I <sub>F</sub>	mA			200
Reverse Voltage	$V_R$	V			2
Output Power	$P_{\text{opt}}$	mW			100
TEC Current	$I_{TEC}$	Α			1.2
TEC Voltage	$V_{TEC}$	V			1.3

#### **Measurement Conditions / Comments**

Stress in excess of one of the Absolute Maximum Ratings may damage the laser. Please note that a damaging optical power level may occur although the maximum current is not reached. These are stress ratings only, and functional operation at these or any other conditions beyond those indicated under Recommended Operational Conditions is not implied.

### Recommended Operational Conditions

Parameter	Symbol	Unit	min	typ	max
Operational Temperature at Case	$T_{case}$	°C	-20		65
Operational Temperature at Laser Chip	$T_LD$	°C	15		45
Forward Current	I <sub>F</sub>	mA			180
Output Power	P <sub>opt</sub>	mW	20		80

Measurement Conditions / Comments

measured by integrated Thermistor

### Characteristics at T<sub>LD</sub> = 25° C at BOL

Parameter	Symbol	Unit	min	typ	max
Center Wavelength	$\lambda_{C}$	nm	779	780	781
Target Wavelength	$\lambda_{\text{T}}$	nm		780.24	
Linewidth (FWHM)	$\Delta\lambda$	MHz		0.6	1
Sidemode Supression Ratio	SMSR	dB	30	45	
Temperature Coefficient of Wavelength	dλ / dT	nm / K		0.06	
Current Coefficient of Wavelength	dλ / dl	nm / mA		0.003	
Mode-hop free Tuning Range	$\Delta \lambda_{\text{tune}}$	pm	25		

#### Measurement Conditions / Comments

ivicasurement Conditions / Comments
see images on page 4
reached within $T_{LD}$ = 15 ° 45° C at 80 mW
$P_{opt} = 80 \text{ mW}$
$P_{opt} = 80 \text{ mW}$
> 10 GHz, at target wavelength

© All rights reserved by eagleyard Photonics GmbH. This data sheet will be electronically administered and is subject to change without notice. Uncontrolled copy when printed.





Revision 0.50

## SINGLE FREQUENCY LASER DIODES Distributed Feedback Laser



Characteristics at T <sub>LD</sub> = 25° C	at BOL				cont'd
Parameter	Symbol	Unit	min	typ	max
Laser Current @ P <sub>opt</sub> = 80 mW	$I_{LD}$	mA			180
Slope Efficiency	η	W/A	0.6	8.0	1.1
Threshold Current	I <sub>th</sub>	mA			70
Divergence parallel (FWHM)	$\Theta_{  }$	0		8	
Divergence perpendicular (FWHM)	$\Theta_{\perp}$	0		21	
Degree of Polarization	DOP	%		90	

Measurement Conditions / Comments
iviedsurement Conditions / Comments
parallel to Pin 1 - Pin 6 plane (see p. 3)
perpendicular to Pin 1 - Pin 6 plane (see p. 3)
$P_{opt} = 80$ mW; E field perpendicular to Pin 1 - 6 plane

Symbol	Unit	min	typ	max
I <sub>mon</sub> / P <sub>opt</sub>	μΑ/mW	tbd		tbd
				., ., ., .,

Леаsı	urement Conditions / Comments
$J_R =$	5 V

Parameter	Symbol	Unit	min	typ	max
Current	I <sub>TEC</sub>	А		tbd	
Voltage	$U_TEC$	V		tbd	
Power Dissipation (total loss at case)	P <sub>loss</sub>	W		tbd	
Temperature Difference	ΔΤ	K			tbd

Measurement Conditions / Comments
$P_{opt} = 80$ mW, $\Delta T = 20$ K
$P_{opt} = 80$ mW, $\Delta T = 20$ K
$P_{opt} = 80$ mW, $\Delta T = 20$ K
$P_{opt} = 80 \text{ mW}, \Delta T =  Tcase - TLD $

Parameter	Symbol	Unit	min	typ	max
Resistance	R	kΩ		10	
Beta Coefficient	β			tbd	
Steinhart & Hart Coefficient A	А			tbd	
Steinhart & Hart Coefficient B	В			tbd	
Steinhart & Hart Coefficient C	C			tbd	

Measurement Conditions / Comments						
$T_{LD} = 25^{\circ} C$						
$R_1/R_2 = e^{\beta(1/T_1-1/T_2)}$ at $T_{LD} =$	0° 50° C					
$1/T = A + B(\ln R) + C(\ln R)^3$						
T: temperature in Kelvin						
R: resistance at T in Ohm						

Ordering Information:



800 Village Walk #316 Guilford, CT 06437 Ph: 203-401-8093

Email orders to: sales@xsoptix.com Fax orders to: 800-878-7282

© All rights reserved by eagleyard Photonics GmbH. This data sheet will be electronically administered and is subject to change without notice. Uncontrolled copy when printed.

Thermistor (Standard NTC Type)



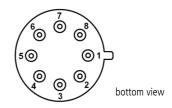


Revision 0.50

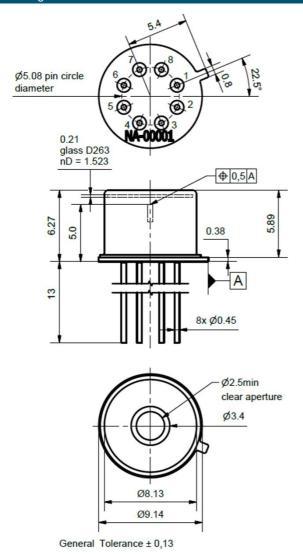
# **SINGLE FREQUENCY LASER DIODES Distributed Feedback Laser**



Pin Assignment							
1	Laser Diode Anode	5	Thermistor				
2	Laser Diode Cathode	6	Thermistor				
3	Thermoelectric Cooler (-)	7	Photo Diode Anode				
4	Thermoelectric Cooler (+)	8	Photo Diode Cathode				
All	8 pins are isolated from case.						



### Package Drawings



AIZ-19-0129-1426B





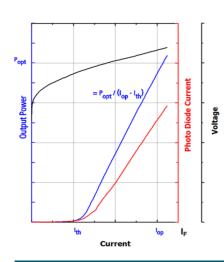
Revision 0.50

## SINGLE FREQUENCY LASER DIODES Distributed Feedback Laser

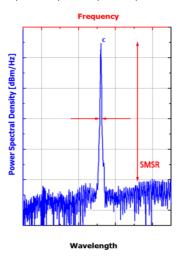


### Typical Measurement Results

Output Power vs. Current



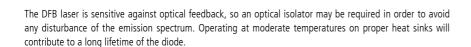
Spectra at Specified Optical Output Power



Performance figures, data and any illustrative material provided in this specification are typical and must be specifically confirmed in writing by eagleyard Photonics before they become applicable to any particular order or contract. In accordance with the eagleyard Photonics policy of continuous improvement specifications may change without notice.

### Unpacking, Installation and Laser Safety

Unpacking the laser diodes should only be done at electrostatic safe workstations (EPA). Though protection against electro static discharge (ESD) is implemented in the laser package, charges may occur at surfaces. Please store this product in its original package at a dry, clean place until final use. During device installation, ESD protection has to be maintained.



Avoid direct and/or indirect exposure to the free running beam. Collimating and focussing the free running beam with optics as common in optical instruments will increase threat to the human eye.

Performance figures, data and any illustrative material provided in this specification are typical and must be specifically confirmed in writing by eagleyard Photonics before they become applicable to any particular order or contract. In accordance with the eagleyard Photonics policy of continuous improvement specifications may change without notice.







INVISIBLE LASER RADIATION
AVOID EYE OR SKIN EXPOSURE
TO DIRECT OR SCATTERED RADIATION
CLASS 4 LASER PRODUCT
WAVELENGTH 780 nm
MAX. OUTPUT POWER 100 mW





